# NSN 5962-01-414-2212

Memory Microcircuit - Page 1 of 1



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# Maximum Power Dissipation Rating:

1.0 watts

**Operating Tempurature Range:** 

-55.0/+125.0 degrees celsius

# End Application:

F-16 acft

### **Features Provided:**

Electrostatic sensitive and monolithic

### Inclosure Material:

Silicon

#### Inclosure Configuration:

Leadless flat pack

#### Output Logic Form:

Complementary-metal oxide-semiconductor logic

#### Criticality Code Justification:

Cbbl

#### **Terminal Surface Treatment:**

Solder

### **Product Name:**

Microcircuits, memory, digital, cmos 32k x 8 eeprom, monolithic silicon

## Voltage Rating And Type Per Characteristic:

-0.3 volts total supply and 6.3 volts total supply

## Time Rating Per Chacteristic:

90.00 nanoseconds access

#### Memory Device Type:

Eeprom

#### **Special Features:**

Case designator per mil-std1835 cqcc1-n32; 3 ms write speed, byte/page data polling/toggle bit end of write indicator, 10, 000 cycles endurance

#### Test Data Document:

96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

32 leadless

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Shelf Life:
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N/a

### Unit Of Measure:

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#### Demilitarization:

No

Fiig:

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